

Am100474

1024 x 4 IMOX™ ECL Bipolar RAM

PRELIMINARY

Am100474

DISTINCTIVE CHARACTERISTICS

- Fast access time (10 ns) — improves system cycle speeds.
- Fully compatible with 100K series ECL logic — no board changes required.
- Enhanced output voltage level compensation providing 6X (improvement in) V_{OL} and V_{OH} stability over supply and temperature ranges.
- Internally voltage-compensated providing flat AC performance.
- Emitter follower outputs — easy wire-ORing
- Power dissipation decreases with increasing temperature.

GENERAL DESCRIPTION

The Am100474-10, Am100474-15 and Am100474-25 are fully decoded 4096-bit ECL RAMs, organized 1024 words by 4 bits. Word selection is achieved by means of a 10-bit address, A_0 through A_9 . Easy memory expansion is provided by an active LOW chip select (\overline{CS}) input and unterminated OR-tieable emitter follower outputs.

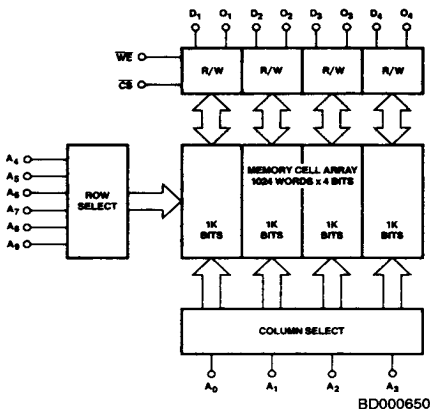
An active LOW write enable (\overline{WE}) controls the write/read operation of the memory. When the chip select and write

enable lines are LOW, the data inputs ($D_1 - D_4$) are written into the addressed memory word.

Reading is performed with the chip select line LOW and the write enable line HIGH. The information stored in the addressed word is read out on the noninverting outputs, $O_1 - O_4$.

During the writing operation, or when the chip select line is HIGH, the output of the memory goes to a LOW state.

BLOCK DIAGRAM



MODE SELECT TABLE

Input		Output		Mode
\overline{CS}	\overline{WE}	D_{IN}	D_{OUT}	
H	X	X	L	Not Selected
L	L	L	L	Write "0"
L	L	H	L	Write "1"
L	H	X	D_{OUT}	Read

H = HIGH
L = LOW
X = Don't Care

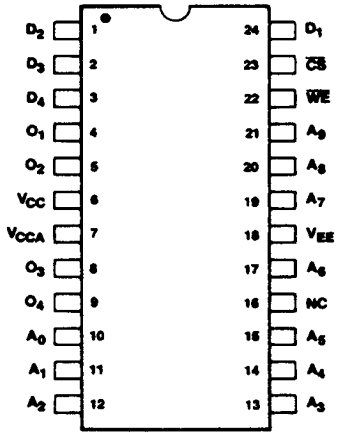
PRODUCT SELECTOR GUIDE

Highlights of Key Performance Parameters (Commercial)

Part Number	Am100474-10	Am100474-15	Am100474-25
Address Access Time (t_{AA})	10 ns	15 ns	25 ns
Write Pulse Width (t_W)	12 ns	15 ns	25 ns
Write Recovery (t_{WR})	14 ns	17 ns	27 ns
Chip Select Access/Recovery and Write Disable Times (t_{ACS} , t_{RCS} , t_{WS})	8 ns	8 ns	10 ns
Power Supply (IEE)	230 mA	200 mA	200 mA

CONNECTION DIAGRAMS Top View

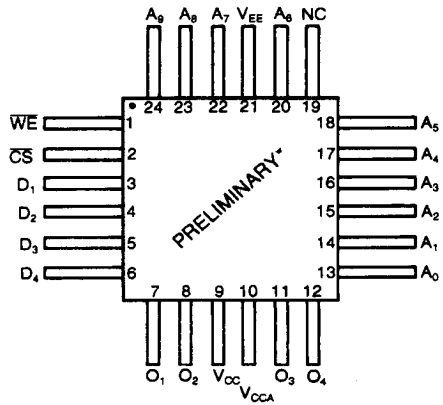
DIP



CD000940

Note: Pin 1 is marked for orientation.

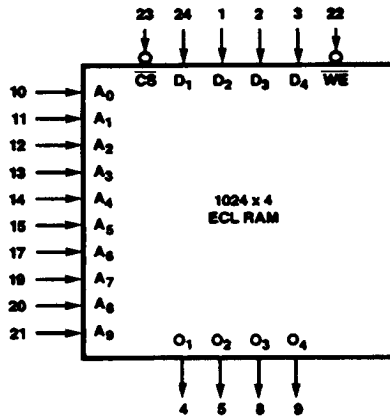
Flatpak



CD006022

*Preliminary. Subject to Change.

LOGIC SYMBOL*



LS000262

V_{CC} = Pin 6
V_{CCA} = Pin 7
V_{EE} = Pin 18
NC = Pin 16

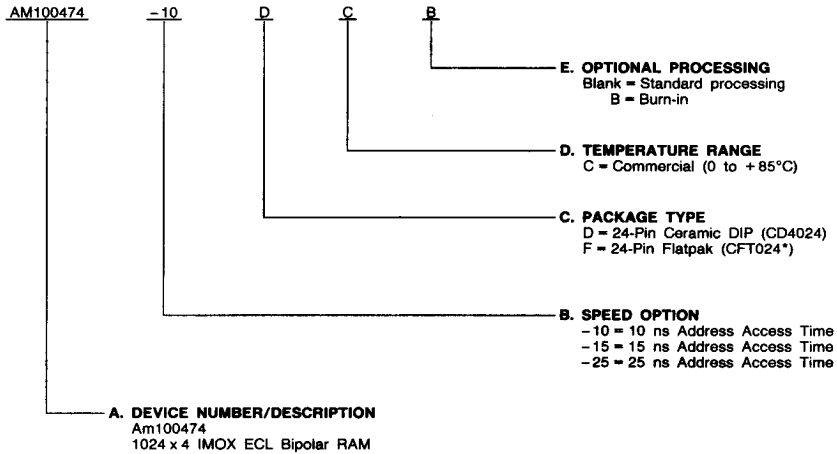
*Pin numbers apply to DIP.

ORDERING INFORMATION

Standard Products

AMD standard products are available in several packages and operating ranges. The order number (Valid Combination) is formed by a combination of:

- A. Device Number**
- B. Speed Option** (if applicable)
- C. Package Type**
- D. Temperature Range**
- E. Optional Processing**



*Preliminary. Subject to Change.

Valid Combinations

Valid Combinations	
AM100474-10	DC, DCB FC, FCB
AM100474-15	
AM100474-25	

Valid Combinations list configurations planned to be supported in volume for this device. Consult the local AMD sales office to confirm availability of specific valid combinations, to check on newly released combinations, and to obtain additional data on AMD's standard military grade products.

ABSOLUTE MAXIMUM RATINGS

Storage Temperature	-65 to +150°C
Case Temperature with Power Applied	-55 to +125°C
V _{EE} Pin Potential to GND Pin	-7.0 V to +0.5 V
Input Voltage (DC)	V _{EE} to +0.5 V
Output Current (DC Output HIGH)	-30 mA to +0.1 mA

Stresses above those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to absolute maximum ratings for extended periods may affect device reliability.

OPERATING RANGES

Commercial (C) Devices (Note 2)	
Temperature	0 to +85°C
Supply Voltage	-5.7 V to -4.2 V

Operating ranges define those limits between which the functionality of the device is guaranteed.

DC CHARACTERISTICS (V_{EE} = -4.5 V, V_{CC} = GND (Note 2))

Parameter Symbol	Parameter Description	Test Conditions (Note 2)	B (Note 3)	Typ. (Note 1)	A (Note 3)	Units
V _{OH}	Output Voltage HIGH	V _{IN} = V _{IHA} or V _{ILB}	-1025		-880	mV
V _{OL}	Output Voltage LOW		-1810		-1620	mV
V _{OHc}	Output Voltage HIGH	V _{IN} = V _{IHB} or V _{ILA}	-1035			mV
V _{OLc}	Output Voltage LOW				-1610	mV
V _{IH}	Input Voltage HIGH	Guaranteed Input Voltage HIGH for All Inputs (Note 4)	-1165		-880	mV
V _{IL}	Input Voltage LOW	Guaranteed Input Voltage LOW for All Inputs (Note 4)	-1810		-1475	mV
I _{IH}	Input Current HIGH	V _{IN} = V _{IHA}			220	μA
I _{IL}	Input Current LOW Chip Select (CS)	V _{IN} = V _{ILB}	0.5		170	μA
	All Other Inputs		-50			
I _{EE}	Power Supply Current (Pin 18)	All Inputs and Outputs Open	Am100474-10	-230		mA
			Am100474-15/-25	-200		

Notes: 1. Typical values are:

V_{EE} = -4.5 V, V_{CC} = V_{CCA} = GND, T_A = 25°C

2. Output Load = 50 Ω and 30 pF to -2.0 V, T = T_A = 0 to +85°C for DIPs. Guaranteed with transverse air flow exceeding 400 linear F.P.M. and 2-minute warm-up period. Approximate resistance values of the package are:

θ_{JA} (Junction-to-Ambient) = 90°C/Watt (still air)

θ_{JA} (Junction-to-Ambient) = 50°C/Watt (at 400 F.P.M. air flow)

T = T_C = 0 to +85°C for Flatpak and LCC packages

θ_{JC} (Junction-to-Case) = 25°C/Watt

3. Definition of symbols and terms used in this product specification: The relative values of the specified conditions and limits will be referenced to an algebraic scale. The extremities of the scale are: "A" the value closest to positive infinity, "B" the value closest to negative infinity.

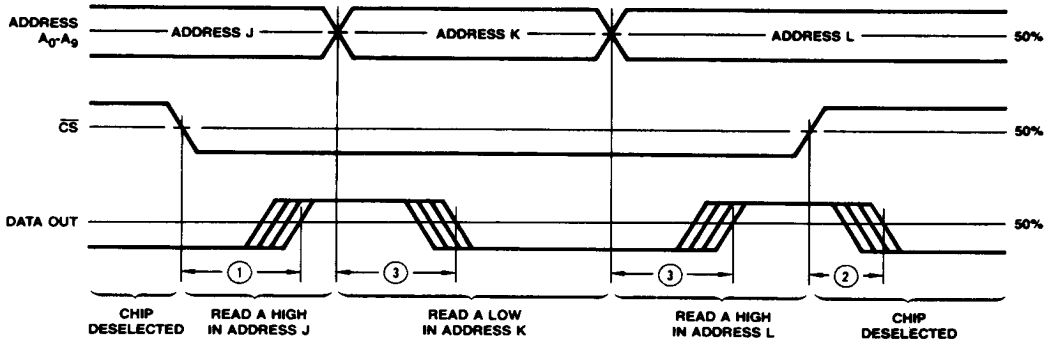
4. These are absolute voltages with respect to device ground pin and include all overshoots due to system and/or tester noise. Do not attempt to test these values without suitable equipment.

3

SWITCHING CHARACTERISTICS $V_{EE} = -4.8$ to -4.2 V, $V_{CC} = \text{GND}$ (Note 2)

No.	Parameter Symbol	Parameter Description	Test Conditions	Am100474-10			Am100474-15			Am100474-25			Units
				Min.	Typ. (Note 1)	Max.	Min.	Typ. (Note 1)	Max.	Min.	Typ. (Note 1)	Max.	
READ MODE													
1	tACS	Chip Select Access Time	Measured at 50% of input to 50% of output			8			8			10	ns
2	tRCS	Chip Select Recovery Time				8			8			10	ns
3	tAA	Address Access Time				10			15			25	ns
WRITE MODE													
4	tW	Write Pulse Width (to Guarantee Writing)	tWSA = tWSA (Min.)	12			15			25			ns
5	tWSD	Data Setup Time Prior to Write		2			2			2			ns
6	tWHD	Data Hold Time After Write		2			2			2			ns
7	tWSA	Address Setup Time Prior to Write	tW = tW (Min.)	2			2			2			ns
8	tWHA	Address Hold Time After Write		2			2			2			ns
9	tWSCS	Chip Select Setup Time Prior to Write		2			2			2			ns
10	tWHCS	Chip Select Hold Time After Write	Measured at 50% of input to 50% of output	2			2			2			ns
11	tWS	Write Disable Time				8			8			10	ns
12	tWR	Write Recovery Time				14			17			27	ns
RISE TIME AND FALL TIME													
13	t _r	Output Rise Time	Measured between 20% and 80% points		2.5			2.5			2.5		ns
14	t _f	Output Fall Time			2.5			2.5			2.5		ns
CAPACITANCE													
15	C _{IN}	Input Pin Capacitance	Measured with a pulse technique on sample basis		4			4			4		pF
16	C _{OUT}	Output Pin Capacitance			7			7			7		pF

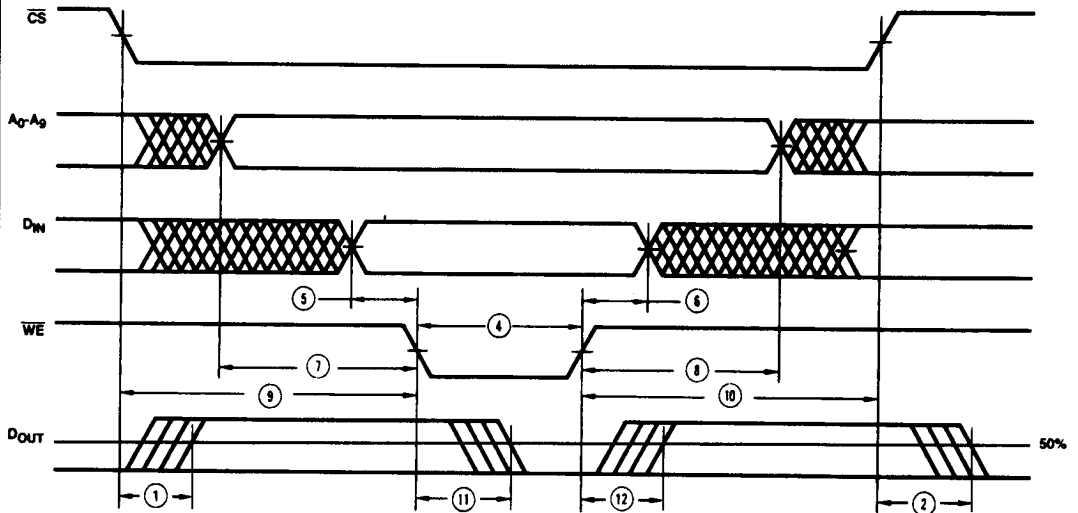
SWITCHING WAVEFORMS (Cont'd.)



Read Mode

WF001173

SWITCHING WAVEFORMS

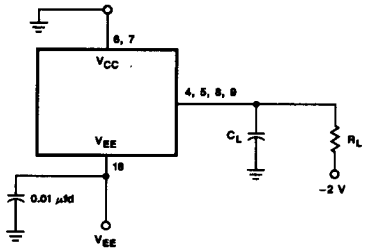


WF001163

Write Mode

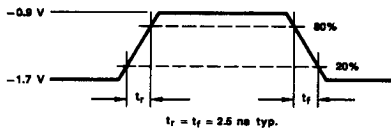
3

SWITCHING TEST CIRCUIT



TC000225

SWITCHING TEST WAVEFORM



TW000310

KEY TO SWITCHING WAVEFORMS

WAVEFORM	INPUTS	OUTPUTS
	MUST BE STEADY	WILL BE STEADY
	MAY CHANGE FROM H TO L	WILL BE CHANGING FROM H TO L
	MAY CHANGE FROM L TO H	WILL BE CHANGING FROM L TO H
	DON'T CARE: ANY CHANGE PERMITTED	CHANGING: STATE UNKNOWN
	DOES NOT APPLY	CENTER LINE IS HIGH IMPEDANCE "OFF" STATE

KS000010

$R_L = 50 \Omega$ termination of measurement system
 $C_L = 30 \text{ pF}$ (including stray jig capacitance)